

Semiconductor Manufacturing Going Green – Role of Chemical Mechanical Planarization (CMP)

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What is CMP and how does CMP contribute to the semiconductor industry?



Zhao L, in All about Interconnects, Semi Engineering, 2017

Kim J Y, Post Cleaning Chemical of Tungsten Chemical Mechanical Planarization for Memory Devices, 2014

Why Post CMP Cleaning?



Inadequate residue removal leads to -

- poor adhesion of subsequent layers
- electrical shortage or leaking
- insufficient device reliability



Post-CMP Cleaning to the Rescue!

W.-T. Tseng, in S. V. Babu, Advances in Chemical Mechanical Planarization (CMP), Woodhead Publishing, 2016

Strategies for Post-CMP cleaning of Cu and Co films



Source: Jihoon Seo, S. S. R. K. Hanup Vegi, and S.V. Babu, ECS J Sold State SC, 8(8), P379-387, 2019

How Do We Reduce the Semiconductor Carbon Footprint?





SEMI member companies joined forces to seek out and partner with the world's top startups to bring new sustainability technologies to semiconductor operations in:

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Environmentally benign products are the need of the hour.

This significantly lowers the energy consumption that is spent on the treatment of various hazardous chemicals before their discharge.

Dean Freeman in "How Do We Reduce the Semiconductor Carbon Footprint?", 3DInCites blog, SEMI.

Choosing the apt chemistry – effective and safe too!

	Chelating Agent	Stability Constant ^{*,*} (Co ²⁺) log [K _{eq} (mol ⁻¹)]	25	Carboxyl functional group Amine functional group
Oxalic Acid Glycine Citric Acid		4.7	, E	
		5.2	1) 15 Au	
		4.4	- 10 -	\backslash
	EDTA	16.3	articl	
	En	14	-	
Aliphatic diamine as # of mo chelating agent comple		# of metal complexes*		2 3 4 Number of functional group
Ethylenediamine (DE) 1,3 propane diamine (DP) 1,4 butane diamine (DB) 1,6 hexane diamine (DH)		>3000 182 18 0	Ability to chelate decreases	Are the long chain amines effective for the removal of organic residues?

• Our primary goal while developing post-CMP cleaning solution is to break the metal complex bond by promoting ligand exchange between the chelating agent and inhibitor molecule with the metal ion and control corrosion, while we choose less toxic chemistries.

▶ Based on the literature, not all amines can readily form complexes with metal ions. Hence, choosing the right amine as the chelating agent in the cleaning solution is important.

A. E. Martell, NIST critically selected stability constants of metal complexes database, National Institute of Standards & Tech(1998); Lutsenko et al., Complexation Zn²⁺ and Co^{2+/3+} with primary diamines: Synthesis, structure and thermal properties, Polyhedron 190 (**2020**). Lee et al, The effect of TAD based cleaning solution on post Cu CMP process, Microelectronic Engineering 162 (2016).

Amines identified for the study



▶ Primary amines of different alkyl chain lengths and amines consisting of both primary and secondary amine groups are chosen to study their ability to break the metal complex.

▶ In this study, we refer to DE and DP as short-chain amines and DB and DH as long-chain amines.

► Toxicity of these amines are in the order DE > DP > DB > DH, with DE being most toxic. Among the secondary amines, TAD is the least toxic compared to others, hence preferred in the post-CMP cleaning chemistry.

Summary

	DE	DP	DB	DH	DETA	TAD
Type of amine	Linear, Short chain	Linear, Short chain	Linear, Long chain	Linear, Long chain	Linear, Short chain	Linear, Long chain
MW (gm)	60	74	88	116	103	189
# of amine functional groups	2	2	2	2	3	5
Mass fraction of amine groups	0.53	0.43	0.36	0.28	0.47	0.41
I _{corr} - Co film (μΑ/cm²)	180	120	1	1	120	40
Co Cleaning Efficiency	High	Low	Very Low	Very Low	High	High
Toxicity	Most toxic	Toxic	Toxic	Toxic	Toxic	Least toxic

▶ While the long chain amines (DB and DH) inhibit film corrosion, the short chain amines (DE and DP) promote film corrosion.

Amine functional groups also help in modulating the metal film corrosion currents that helps in removing the adsorbed organic residue layer from the film surfaces.

Both DETA and TAD show high cleaning efficiency and preserve the film surface quality post cleaning. Moreover, TAD is less toxic and preferred in the post-CMP cleaning chemistry.